NSN 5961-01-228-5605

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-228-5605 **Inclosure Material:** Glass **Overall Length:** 0.260 inches **Terminal Length:** 0.900 inches **Overall Diameter:** 0.180 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, instantaneous and 200.0 working peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 80.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No